Low-ohmic single-pole double-throw analog switch

Rev. 07 — 21 January 2010

**Product data sheet** 

### 1. General description

The NX3L1T3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I<sub>CC</sub>. The NX3L1T3157 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from Z to Y0 or Y1, or from Y0 or Y1 to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2. Features

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.6  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0  $\Omega$  (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - HBM JESD22-A114E Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



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## 3. Applications

- Cell phone
- PDA
- Portable media player

## 4. Ordering information

#### Table 1.Ordering information

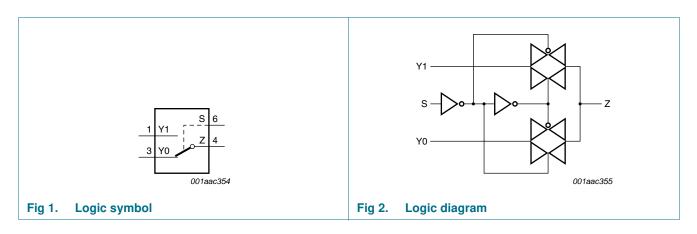
Type number	Package										
	Temperature range Name Description										
NX3L1T3157GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363							
NX3L1T3157GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886							

## 5. Marking

Table 2.	Marking codes <sup>[1]</sup>	
Type num	nber	Marking code
NX3L1T3	157GW	MI
NX3L1T3	157GM	MI

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

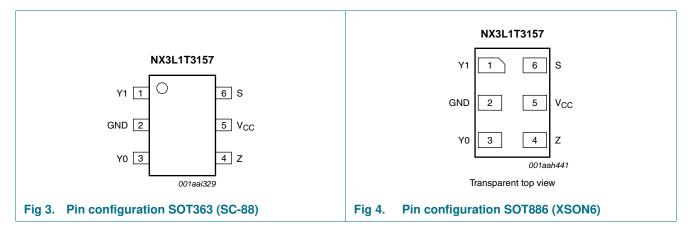
## 6. Functional diagram



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## 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V <sub>CC</sub>	5	supply voltage
S	6	select input

## 8. Functional description

#### Table 4.Function table

Input S	Channel on
L	YO
Н	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

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## 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{l} < -0.5$ V or $V_{l} > V_{CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u> _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V <sub>SW</sub>	switch voltage		<u>[1]</u> 0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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## **11. Static characteristics**

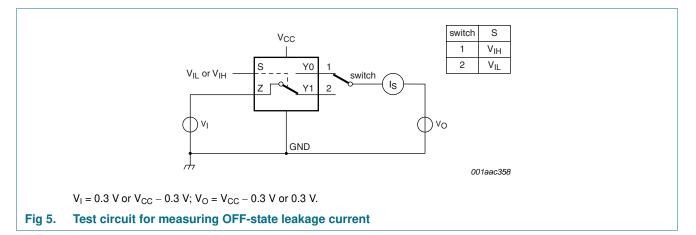
#### Table 7. Static characteristics

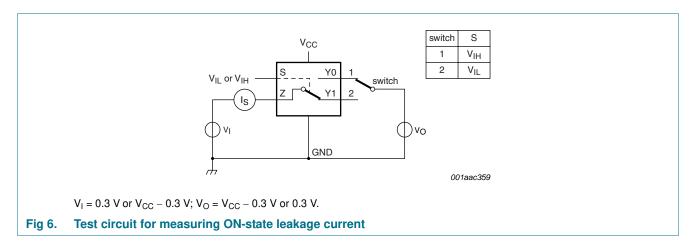
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Τ <sub>ε</sub>	<sub>amb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I	input leakage current	select input S; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
$I_{S(OFF)}$	OFF-state leakage	Y0 and Y1 port; see <u>Figure 5</u>							
	current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state	Z port; see Figure 6							
	leakage current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	$\pm 5$	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
$\Delta I_{CC}$	additional	$V_{SW} = GND \text{ or } V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	130	-	-	-	-	pF

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### 11.1 Test circuits





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### 11.2 ON resistance

#### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

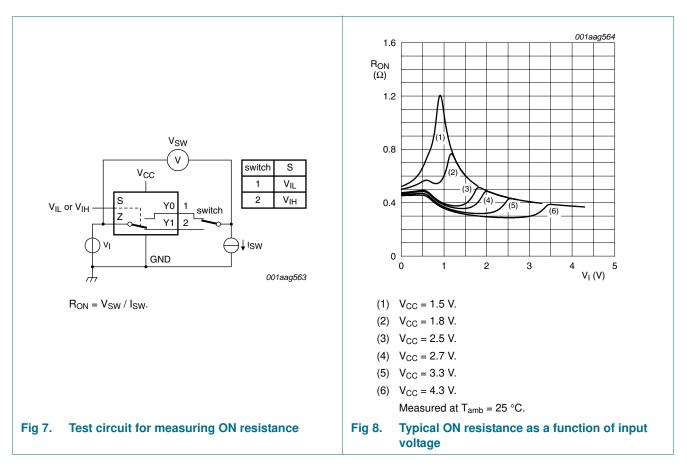
Symbol	Parameter	Conditions	T <sub>amb</sub> =	: −40 °C to	o +85 °C	$T_{amb}$ = -40 °	C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100$ mA; see Figure 7						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	<u>2]</u>					
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V <sub>CC</sub> = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	$V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	3]					
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at  $T_{amb}$  = 25 °C.

[2] Measured at identical  $V_{CC}$ , temperature and input voltage.

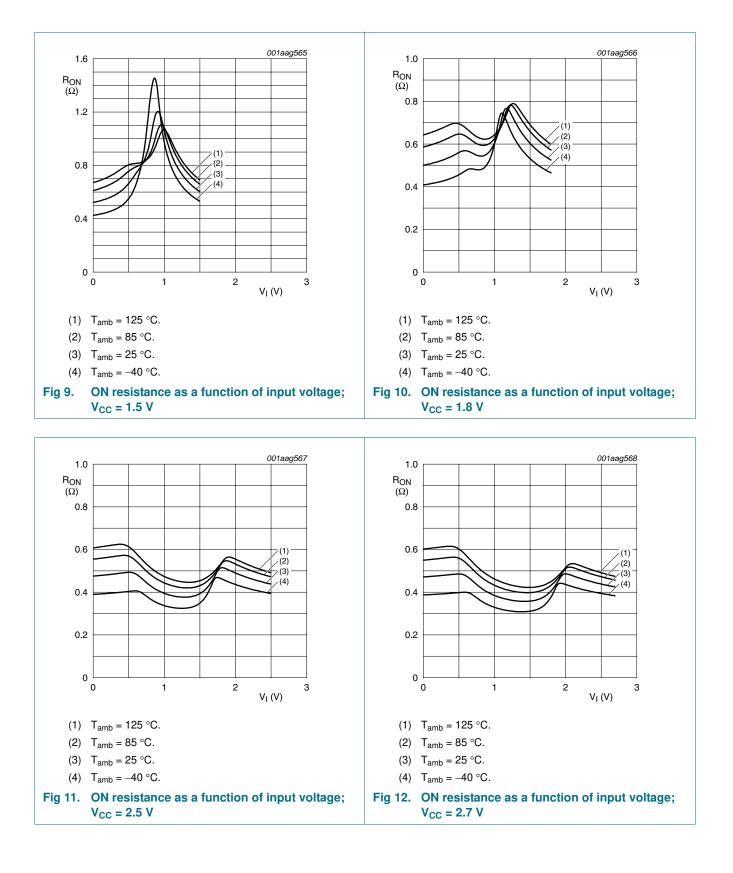
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

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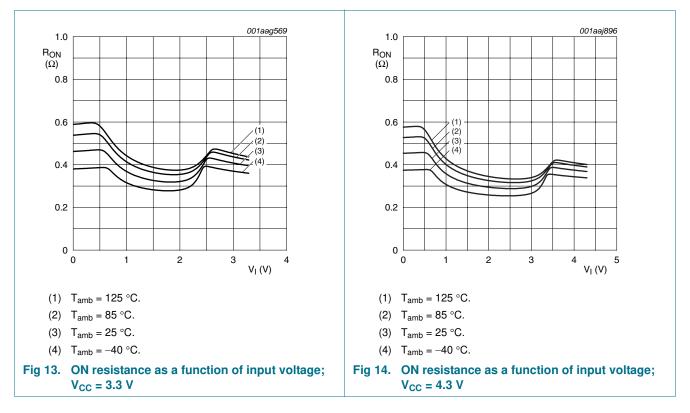
### 11.3 ON resistance test circuit and graphs

# NX3L1T3157



# NX3L1T3157

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### 12. Dynamic characteristics

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions		25 °C		-40	°C to +12	5 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Мах (85 °С)	Max (125 °C)	
t <sub>en</sub>	enable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	50	90	-	120	120	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	36	70	-	80	90	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	24	45	-	50	55	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	22	40	-	45	50	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	22	40	-	45	50	ns
t <sub>dis</sub>	disable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	32	70	-	80	90	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	20	55	-	60	65	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	12	25	-	30	35	ns
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	-	10	20	-	25	30	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	10	20	-	25	30	ns

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Symbol	DIParameterConditions25 °C			–40 °C to +125 °C			Unit			
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	-
t <sub>b-m</sub> break-before-make time	see Figure 16	[2]								
	time	V <sub>CC</sub> = 1.4 V to 1.6 V		-	19	-	9	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	13	-	4	-	-	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V		-	10	-	3	-	-	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

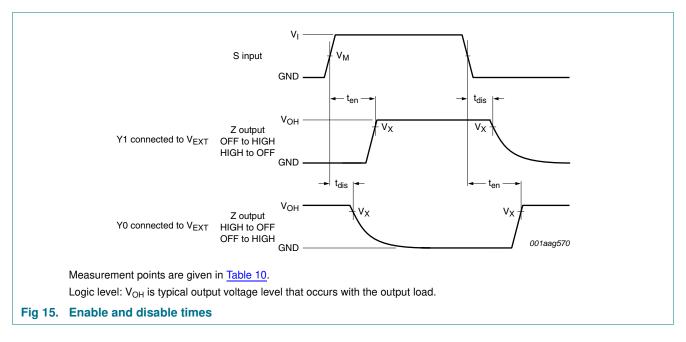
#### Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

### 12.1 Waveform and test circuits

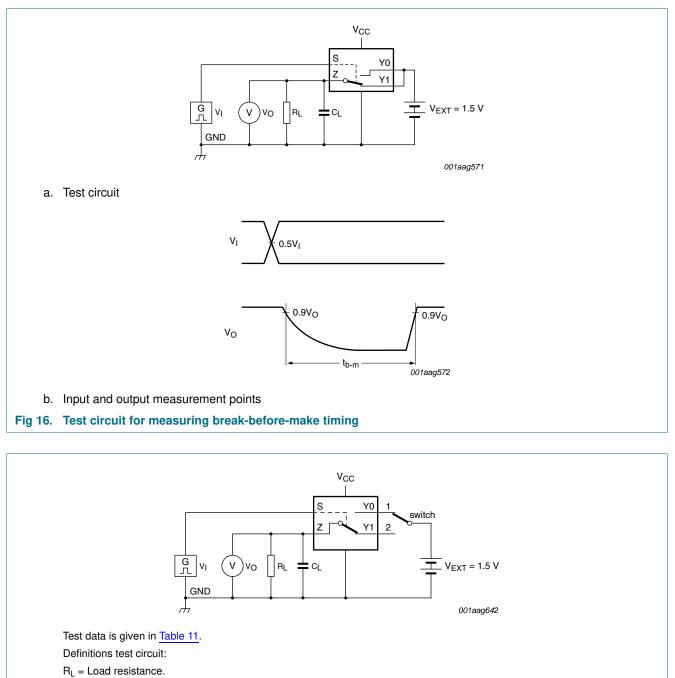


#### Table 10. Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

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C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $V_{EXT}$  = External voltage for measuring switching times.

#### Fig 17. Load circuit for switching times

#### Table 11. Test data

Supply voltage	Input		voltage Input Load		Load	
V <sub>cc</sub>	V <sub>I</sub> t <sub>r</sub> , t <sub>f</sub>		CL	RL		
1.4 V to 4.3 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω		

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### 12.2 Additional dynamic characteristics

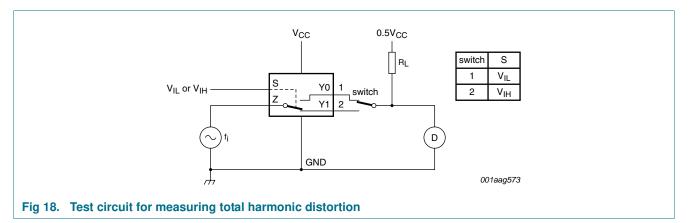
#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns;  $T_{amb} = 25$  °C.

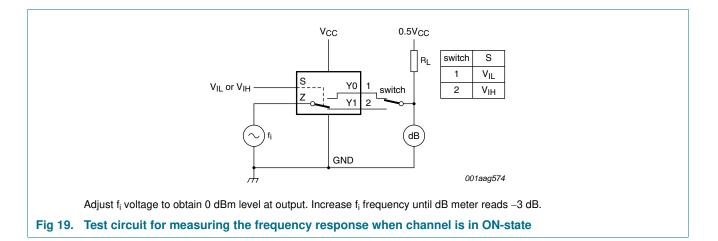
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
THD	total harmonic distortion	$f_i$ = 20 Hz to 20 kHz; $R_L$ = 32 $\Omega$ ; see <u>Figure 18</u>	[1]			
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)	-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)	-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
$f_{(-3dB)}$	–3 dB frequency response	$R_L = 50 \Omega$ ; see Figure 19	[1]			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	60	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$	[1]			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 21				
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	0.2	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	0.3	-	V
Q <sub>inj</sub>	charge injection	$      f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 22}}{10000000000000000000000000000000000$				
		$V_{CC} = 1.5 V$	-	3	-	рС
		$V_{CC} = 1.8 V$	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		V <sub>CC</sub> = 3.3 V	-	9	-	рС
		$V_{CC} = 4.3 V$	-	15	-	рС

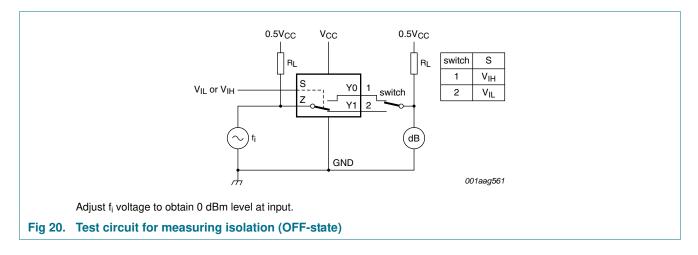
[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

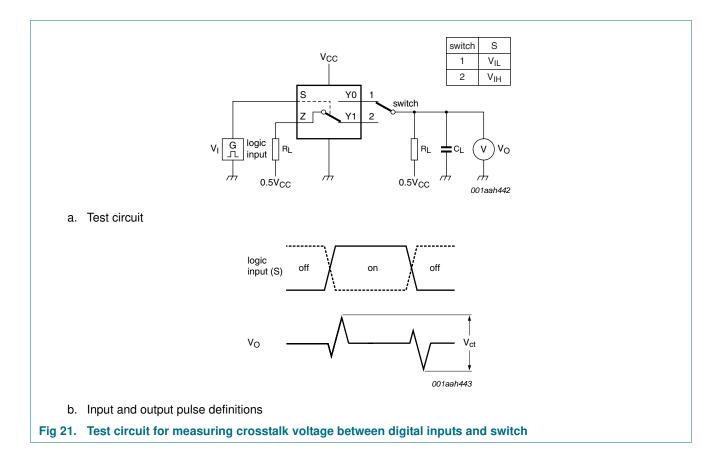
### 12.3 Test circuits



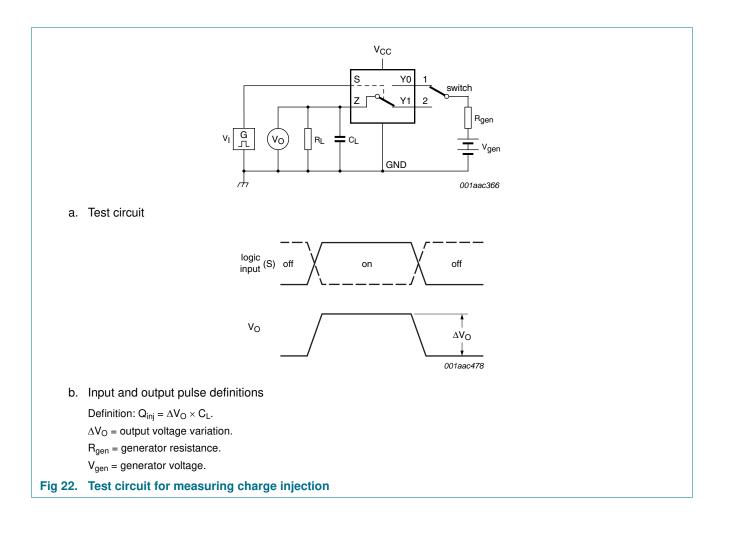
# NX3L1T3157







# NX3L1T3157



# NX3L1T3157

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## 13. Package outline

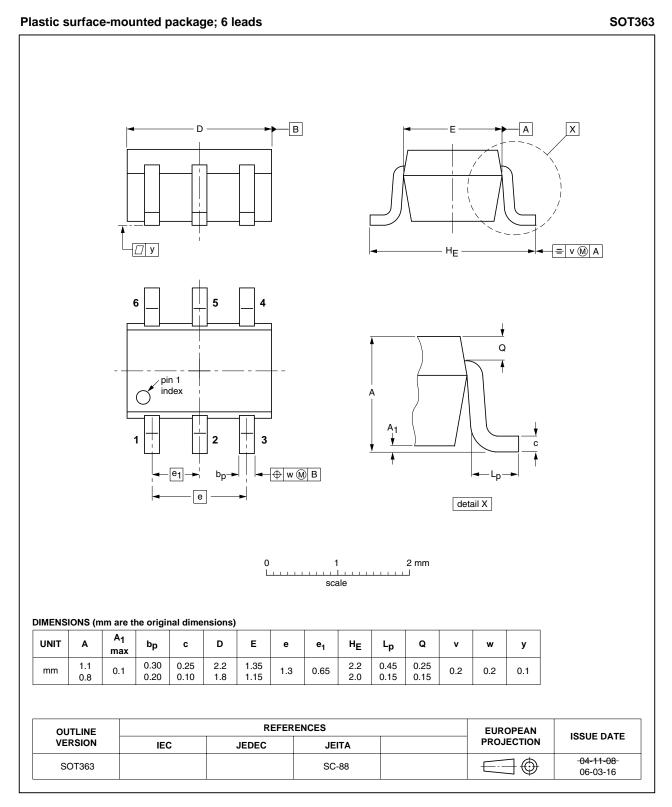
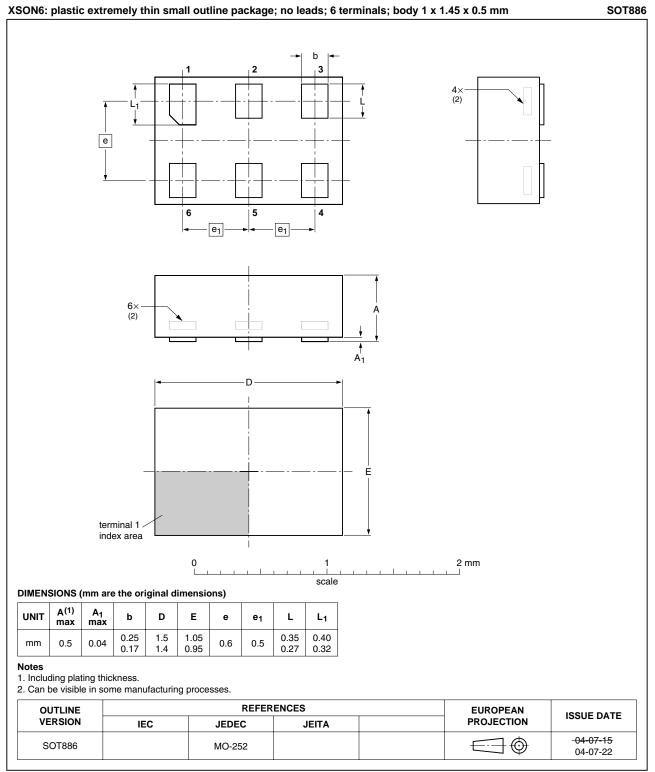


Fig 23. Package outline SOT363 (SC-88)

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## Fig 24. Package outline SOT886 (XSON6)

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## 14. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		
PDA	Personal Digital Assistant		

## 15. Revision history

Table 14. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1T3157_7	20100121	Product data sheet	-	NX3L1T3157_6
Modifications:	<u>Section 2</u> : I	EC61000-4-2 added.		
	<ul> <li><u>Table 8</u>: ON</li> </ul>	l resistance (flatness) chang	ged at $V_{CC}$ = 4.3 V.	
NX3L1T3157_6	20090415	Product data sheet	-	NX3L1T3157_5
NX3L1T3157_5	20080728	Product data sheet	-	NX3L1T3157_4
NX3L1T3157_4	20080718	Product data sheet	-	NX3L1T3157_3
NX3L1T3157_3	20080408	Product data sheet	-	NX3L1T3157_2
NX3L1T3157_2	20080306	Product data sheet	-	NX3L1T3157_1
NX3L1T3157_1	20080103	Product data sheet	-	-

Low-ohmic single-pole double-throw analog switch

## 16. Legal information

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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# NX3L1T3157

Low-ohmic single-pole double-throw analog switch

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